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Thermal Stabilities, Electronic Structures and Optical Properties of Intrinsic Defects and Dopant Cerium in $\text{Ca}_4\text{F}_2\text{Si}_2\text{O}_7$

Jun Wen^{a,b,*}, Yau-Yuen Yeung^{a,*}, Lixin Ning^c, Chang-Kui Duan^d, Yucheng Huang^c, Jie Zhang^b,
Min Yin^d

^a Department of Science and Environmental Studies, The Education University of Hong Kong, 10 Lo Ping Road,
Tai Po, NT, Hong Kong, China

^b School of Physics and Electronic Engineering, Anqing Normal University, Anqing 246133, China

^c Center for Nano Science and Technology, Department of Physics, Anhui Normal University, Wuhu 241000, China

^d Department of Physics, University of Science and Technology of China, Hefei 230026, China

The thermal stabilities, electronic structures and optical properties of intrinsic defects and dopant Ce^{3+} in $\text{Ca}_4\text{F}_2\text{Si}_2\text{O}_7$ host are studied by using density functional theory (DFT) calculations (with PBE and hybrid PBE0 functionals) and wave function-based embedded cluster *ab-initio* calculations (at the CASSCF/CASPT2/RASSI-SO level). The calculated formation energies reveal that anion vacancies (V_{O} and V_{F}) are always much more energetically favorable than cation vacancies (V_{Ca} and V_{Si}) in $\text{Ca}_4\text{F}_2\text{Si}_2\text{O}_7$ host, which is generally prepared under reducing atmospheres. According to the thermodynamic transition energy levels of intrinsic defects readily generated in undoped $\text{Ca}_4\text{F}_2\text{Si}_2\text{O}_7$ (e.g. anion vacancies and antisite defects), we may identify the defect-induced host absorption and emission, whose exact origins are unclear previously. Moreover, on the basis of *ab-initio* calculated energies and relative oscillator strengths of the $4f \rightarrow 5d$ transitions of Ce^{3+} at calcium sites with charge-compensating defect O_{F} in their local environments, the excitation bands in the experimental spectra of Ce^{3+} -doped $\text{Ca}_4\text{F}_2\text{Si}_2\text{O}_7$ phosphors are also assigned. The main purpose of this work is to understand luminescence mechanisms of intrinsic defects and extrinsic dopants in the hosts for phosphors by using first-principles approaches.

Keywords: Thermal stabilities; Intrinsic defects; $4f \rightarrow 5d$ transitions; Ce^{3+} ; First-principles; Phosphors

* Corresponding Author.

E-mail address: wenjunkd@mail.ustc.edu.cn (J. Wen).

yyyeung@eduhk.hk (Y.-Y. Yeung).

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